



Voidless Hermetically Sealed High Voltage Rectifier Qualified per MIL-PRF-19500/279

Qualified Levels: JAN and JANTX (1N3644 – 1N3647 only)

DESCRIPTION

These "standard recovery" high voltage rectifier diode series are military qualified to MIL-PRF-19500/279 for the 1N3644 through 1N3647 part numbers. They are ideal for high voltage, high-reliability applications where a failure cannot be tolerated. These 0.10 and 0.25 Amp rated rectifiers with working peak reverse voltages from 1000 to 10,000 volts are hermetically sealed with voidless-glass construction.

Important: For the latest information, visit our website http://www.microsemi.com.

FEATURES

- JEDEC registered 1N3643 1N3647, 1N4254 1N4257, and 1N5181 1N5184 series.
- · Voidless hermetically sealed glass package.
- Triple-layer passivation.
- Lowest reverse leakage available.
- Absolute high voltage / high temperature stability.
- JAN and JANTX qualifications are available only for 1N3644 1N3647 per MIL-PRF-19500/279.
- RoHS compliant versions available (commercial grade only).

APPLICATIONS / BENEFITS

- High voltage standard recovery rectifiers 1000 to 10,000 V.
- Military and other high-reliability applications.
- Applications include bridges, half-bridges, catch diodes, voltage multipliers, X-ray machines, power supplies, transmitters, and radar equipment.
- High forward surge current capability.
- Extremely robust construction.
- Low thermal resistance.
- Inherently radiation hard as described in Microsemi MicroNote 050.



S Package

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MAXIMUM RATINGS @ T_A= 25 °C unless otherwise specified

Parameters/Test Conditions	Symbol	Value	Unit		
Junction and Storage Temperature	T _J & T _{STG}	-65 to +175	°C		
Steady State Power Dissipation @ T _A = 25 °C	P_D	1.5	W		
Thermal Resistance Junction-to-Lead @ 3/8 inch from body	ReJL	38	°C/W		
Working Peak Reverse Voltage:	1N3643		1000		
	1N3644 & 1N4254		1500		
	1N3645 & 1N4255		2000		
1N3646 & 1N4256 1N3647 & 1N4257 1N5181			2500	V	
		V_{RWM}	3000		
			4000		
	1N5182		5000		
	1N5183		7500		
	1N5184		10,000		
Reverse Voltage:	1N3644		1050	V	
	1N3645	V_{R}	1400		
	1N3646		1750		
	1N3647		2100		
Average Rectified Forward Current:					
1N3643 - 1N3647	@ T _A = 55 °C	I _O 0.250		Α	
	@ T _A = 100 °C		0.100		
1N4254 – 1N4257	@ $T_A = 55 {}^{\circ}C$	Io	0.250	Α	
	@ T _A = 100 °C		0.150		
1N5181 – 1N5184	@ T _A = 55 °C	Io	0.100	Α	
	@ T _A = 100 °C	-	0.060		
Solder Temperature @ 10 s		T _{SP}	260	°C	

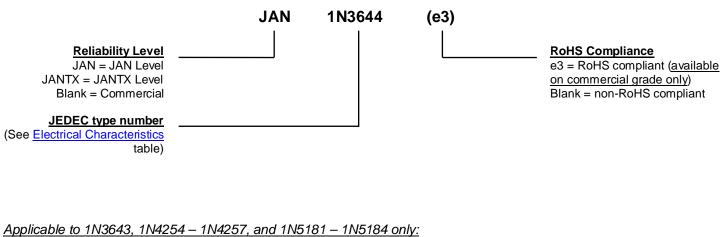
MECHANICAL and PACKAGING

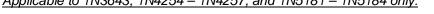
- · CASE: Hermetically sealed voidless hard glass with tungsten slugs.
- TERMINALS: Tin/lead or RoHS compliant matte/tin (commercial grade only) over copper.
- MARKING: Part number.
- POLARITY: Cathode indicated by band.
- TAPE & REEL option: Standard per EIA-296. Consult factory for quantities.
- WEIGHT: Approximately 400 milligrams.
- See <u>Package Dimensions</u> on last page.

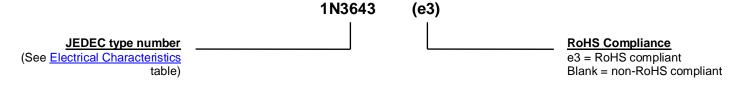


PART NOMENCLATURE

Applicable to 1N3644 thru 1N3647 only:







SYMBOLS & DEFINITIONS					
Symbol	Definition				
Io	Average Rectified Forward Current: The output current averaged over a full cycle with a 50 Hz or 60 Hz sine-wave input and a 180 degree conduction angle.				
I _R	Maximum Leakage Current: The maximum leakage current that will flow at the specified voltage and temperature.				
I _{ZSM}	Maximum Rated Surge Current: The non-repetitive peak value of rated surge current at a specified wave form.				
$V_{(BR)}$	Minimum Breakdown Voltage: The minimum voltage the device will exhibit at a specified current.				
V _F	Maximum Forward Voltage: The maximum forward voltage the device will exhibit at a specified current.				
V_R	Reverse Voltage: The reverse voltage dc value, no alternating component.				
V_{RWM}	Working Peak Reverse Voltage: The maximum peak voltage that can be applied over the operating temperature range.				



ELECTRICAL CHARACTERISTICS

TYPE	MINIMUM BREAKDOWN VOLTAGE V _(BR)	MAXIMUM FORWARD VOLTAGE V _F (See Notes 1 & 2)	REVERSE CURRENT (MAX.) I _R @ V _{RWM}			AVERAGE REVERSE CURRENT I _{R(AV)} @ V _R	MAXIMUM SURGE CURRENT @ 8.3 ms I _{ZSM}	
	Volts	Volts		μΑ			μΑ	Amps
			25 °C	55 °C	125 °C	175 °C	+100°C	
1N3643	-	5.0 (1)	5	-	-	-	-	14
1N3644*	1800	5.0 (1)	5	-	-	-	100	14
1N3645*	2400	5.0 (1)	5	-	-	-	100	14
1N3646*	3000	5.0 (1)	5	-	-	-	100	14
1N3647*	3600	5.0 (1)	5	-	-	-	100	14
1N4254	-	3.5 (2)	1	-	20	-	-	10
1N4255	-	3.5 (2)	1	-	20	-	-	10
1N4256	-	3.5 (2)	1	-	20	-	-	10
1N4257	-	3.5 (2)	1	-	20	-	-	10
1N5181	-	10 (2)	-	5	-	1000	-	4
1N5182	-	10 (2)	-	5	-	1000	-	4
1N5183	-	10 (2)	-	5	-	1000	-	4
1N5184	-	10 (2)	-	5	-	1000	-	4

^{*} Also applicable to JAN and JANTX levels.

NOTE 1: V_F @ 250mA **NOTE 2:** V_F @ 100mA



GRAPHS

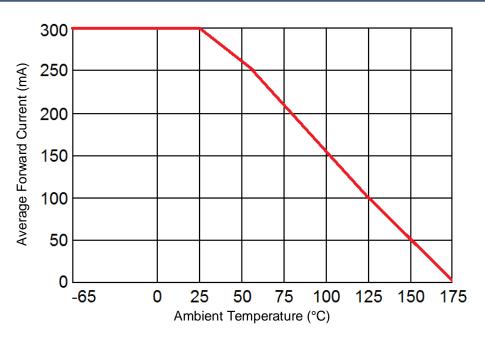


FIGURE 1 1N3643 - 1N3647 and 1N4254 - 1N4257

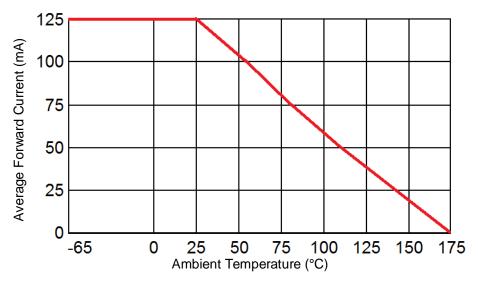
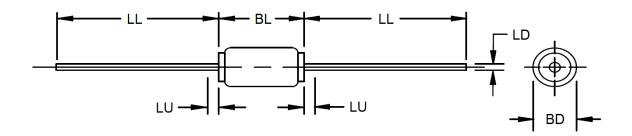


FIGURE 2 1N5181 – 1N5184



PACKAGE DIMENSIONS



NOTES:

- 1. Dimensions are in inches.
- 2. Millimeters are given for general information only.
- Package contour optional with BD and length BL. Heat slugs, if any, shall be included within this cylinder length but shall not be subject to minimum limit of BD.
- 4. The specified lead diameters apply in the zone between .050 inch (1.27 mm) from the diode body and the end of the lead.
- In accordance with ASME Y14.5M, diameters are equivalent to Φx symbology.
- 6. Max dimension BL will be .225" / 5.72mm for 1N5181 1N5184

	DIMENSIONS				
Ltr	INCH		MILLIM	Notes	
	Min	Max	Min	Max	
BD	0.065	0.110	1.65	2.79	3
BL	0.190	0.215	4.83	5.46	3, 6
LD	0.029	0.033	0.74	0.84	
LL	1.00	1.25	25.40	31.75	
LU		0.050		1.27	4